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Exploring optoelectronic and photocatalytic properties of $X_2\text{AgBiY}_6$ ($X = \text{NH}_4$, PH_4 , AsH_4 , SbH_4 and $Y = \text{Cl}$, Br): a DFT study

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Ab initio calculations have been used to investigate lead-free double-perovskites (DPs) $X_2\text{AgBiY}_6$ ($X = \text{NH}_4$, PH_4 , AsH_4 , SbH_4 and $Y = \text{Cl}$, Br) for solar-cell-based energy sources. The most recent and improved Becke–Johnson potential (TB–mBJ) has been proposed for the computation of optoelectronic properties. Theoretical and calculated values of the lattice constants obtained by applying the Wu–Cohen generalized gradient approximation (WC–GGA) were found to be in good agreement. The computed bandgap values of $(\text{NH}_4)_2\text{AgBiBr}_6$ (1.574 eV) and $(\text{SbH}_4)_2\text{AgBiBr}_6$ (1.440 eV) revealed their indirect character, demonstrating that they are suitable contenders for visible light solar-cell (SC) technology. Properties like the refractive index, light absorption, reflection, and dielectric constant are all explained in terms of the optical ranges. Within the wavelength range of 620–310 nm, the maximum absorption band has been identified. Additionally, we discover that all chemicals investigated herein have photocatalytic capabilities that can be used to efficiently produce hydrogen at cheap cost using solar water splitting by photocatalysts. In addition, the stability of the compounds was examined using the calculation of mechanical properties.

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1. Introduction

Due to the development of high efficiency and inexpensive materials, the past two decades have been crucial for the study of perovskite solar cells (PSC). Power conversion efficiencies (PCEs) for perovskite solar cells of up to 24.5% have been reported, which are comparable with PCEs for silicon (Si)-based solar cells.^{1,2} Recent perovskite solar cells function similarly to absorber materials made of an inorganic halide perovskite (HP) and a lead-based organic halide. Geisz *et al.*³ produced a multi-junction solar cell (SC) with a productivity greater than 47.1%, which is 11.1% higher than with thin-film-based solar cells. In extremely efficient solar cell applications, including the production of solar fuel and solar hydrogen, hybrid organic–inorganic halide perovskites $\text{CH}_3\text{NH}_3\text{PbX}_3$ ($X = \text{Cl}$, Br , and I) have gained attention.^{4–6} On the other hand, lead-based halide perovskites have challenges with stability, as well as containing a hazardous material (lead), which limits the applications of these materials on a broad scale. Finding reliable and Pb-free

alternative materials is therefore necessary to solve these issues. Therefore, halide double perovskites have received a lot of attention as a result.^{7–17} Halide double perovskites are a vast class of quaternary halides. Opportunities for new solar and photovoltaic materials have been offered by the wide geometric range of these materials. However, when a large number of compounds are examined to determine which are most promising in terms of energy, structure, and electrical properties for solar cell applications, the work grows more challenging. As opposed to the unstable solar absorbent substance $\text{CH}_3\text{NH}_3\text{PbI}_3$ (MAPI), which contains Pb, halide double perovskite compounds like $\text{Cs}_2\text{AgBiX}_6$ ($X = \text{Cl}$ and Br) have gained a lot of interest, leading to a number of experimental and theoretical studies.^{18,19} Filip *et al.*^{20,21} suggested other cation possibilities from hypothetical perovskites such as NH_4 , PH_4 , AsH_4 , SbH_4 , NCl_4 , PF_4 , CH_3PH_3 , *etc.* The thermodynamic stability of numerous halide double perovskites was predicted by Han and his colleagues using density functional theory (DFT).²² All-double perovskite inorganic materials have been investigated as a potential replacement for lead-based perovskites due to their non-toxic qualities and three-dimensional structures. Giustino and Snaith have predicted the formation of new halide double perovskites.¹⁷ From those suggested materials, we selected one class as $X_2\text{AgBiY}_6$ ($X = \text{NH}_4$, PH_4 , AsH_4 , SbH_4 and $Y = \text{Cl}$, Br) with the exception of F and I because of the corresponding substantial bandgap instability. A predicted view of the crystal structure of the stable double perovskite material $X_2\text{AgBiY}_6$ is illustrated in Fig. 1. In this paper, we investigated

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the structural, electronic, photocatalytic, optical, and mechanical characteristics of X_2AgBiY_6 .

2. Computational details

We used the WIEN2k program to carry out our computations using the full-potential linearized augmented plane wave plus local orbitals (FP-LAPW + lo) approach, which constitutes a component of DFT.²³ A more accurate exchange-correlation potential flavour can be acquired using the Wu–Cohen generalized gradient approximation (WC-GGA), and used to evaluate the properties of the material.²⁴ In order to determine an accurate bandgap, we used the WC-GGA with the modified Becke–Johnson (mBJ) correction.^{25,26} For other semiconductors, especially lead halide perovskites, in the past,^{27–31} the mBJ approach produced encouraging band topologies and bandgap values when compared to experimental results. In order to apply the mBJ strategy across WC-GGA to our hypothesized compounds, we first applied it to the experimental data for Cs_2AgBiX_6 ($X = Cl$ and Br), and after that, we implemented this plan for our compounds X_2AgBiY_6 . Electronic and optical characteristics are estimated using k -meshes of $8 \times 8 \times 8$ and $15 \times 15 \times 15$. All structures are optimized when the energy convergence tolerance is 10^{-5} Ry.

3. Results and discussion

The structural characteristics of a compound play a significant role in understanding its varied physical properties. All eight potential compounds for the double perovskite X_2AgBiY_6 ($X =$

NH_4 , PH_4 , AsH_4 , SbH_4 and $Y = Cl$, Br) that we predicted are grouped into four different categories: NH_4^- , PH_4^- , AsH_4^- , and SbH_4^- -based compounds.

Firstly, we performed relaxation as the organic components contain hydrogen. Then, using volume optimization, we were able to extract structural parameters such as the bulk modulus B (GPa) and lattice constant a (Å). Experimental values of the Cs_2AgBiX_6 lattice parameter ($X = Cl$ and Br) has been used as a starting point. Table 1 displays the structural characteristics of the hypothetical compounds as determined using the Birch–Murnaghan equation of states.³² The optimization of X_2AgBiY_6 is presented in Fig. 2. The optimized lattice constants for all compounds range from 10.03 Å to 12.33 Å, which is quite close to the lattice constants of other experimentally synthesized double perovskites, like $Cs_2AgBiCl_6$ and $Cs_2AgBiBr_6$, which are 10.77 Å and 11.27 Å, respectively.¹⁸ $(NH_4)_2AgBiCl_6$ has the greatest optimal bulk modulus, B , of all the compounds with a value of 75.55 GPa. $(SbH_4)_2AgBiBr_6$, on the other hand, has the lowest B value of 27.15 GPa, demonstrating the durability of these double perovskites. Results for these optimized compounds cannot be compared to any theoretical or experimental data. After adjusting the lattice constant, these compounds can be characterized using bandgap values that are comparable to the best hybrid organic–inorganic perovskites.

In order to analyse the electrical behavior of the materials, the band structures are essential. We can study the materials' electronic nature by using band structures to determine if they are metallic or semiconducting, *etc.* The electronic band structure may successfully clarify the physical characteristics of solids including their optical behavior and resistivity, and this knowledge can further assist in the design of solid-state devices like solar cells and transistors, among other applications. In order to comprehend their electronic structure, we calculated the band structures of X_2AgBiY_6 ($X = NH_4$, PH_4 , AsH_4 , SbH_4 and $Y = Cl$, Br). We have observed a definite increase in their bandgap when their bond distance increases going from N to Sb . This is mostly caused by the compound's growing number of deep shells. All of the compounds' bandgaps were computed using an intuitive self-consistent field (SCF) model that took into account spin–orbit coupling (SOC), and on top of that, we used the mBJ technique to adjust the bandgap value to correspond with the experimental values. As a benchmark, we first recalculated the experimental bandgap values for $Cs_2AgBiCl_6$

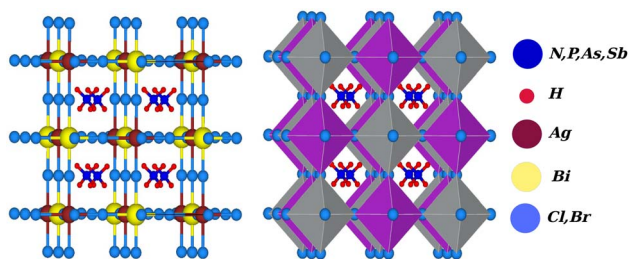


Fig. 1 Predicted crystal structure of X_2AgBiY_6 ($X = NH_4$, PH_4 , AsH_4 , SbH_4 and $Y = Cl$, Br).

Table 1 Lattice parameters, bond distances between A and H ($A = N$, P , As , and Sb) and bandgaps of halide double perovskites X_2AgBiY_6 ($X = NH_4$, PH_4 , AsH_4 , SbH_4 and $Y = Cl$, Br)

Materials	Bond distance $d_{(A-H)}$ (Å)	Lattice parameter (Å)	Bulk modulus B (GPa)	Bandgap (without SOC) E_g (eV)	Bandgap (with SOC) E_g (eV)	Bandgap hybrid (mBJ + SOC) E_g (eV)
$(NH_4)_2AgBiCl_6$	1.08	10.03	75.55	1.51	1.36	2.32
$(NH_4)_2AgBiBr_6$	1.12	10.50	66.87	0.97	0.87	1.75
$(PH_4)_2AgBiCl_6$	1.39	10.94	46.77	1.78	1.43	2.42
$(PH_4)_2AgBiBr_6$	1.43	11.26	44.39	1.28	1.03	1.95
$(AsH_4)_2AgBiCl_6$	1.45	11.47	36.41	1.83	1.52	2.29
$(AsH_4)_2AgBiBr_6$	1.46	11.56	38.95	1.36	1.23	2.15
$(SbH_4)_2AgBiCl_6$	1.66	12.15	26.18	1.80	1.44	2.00
$(SbH_4)_2AgBiBr_6$	1.69	12.32	27.15	1.31	1.03	1.44



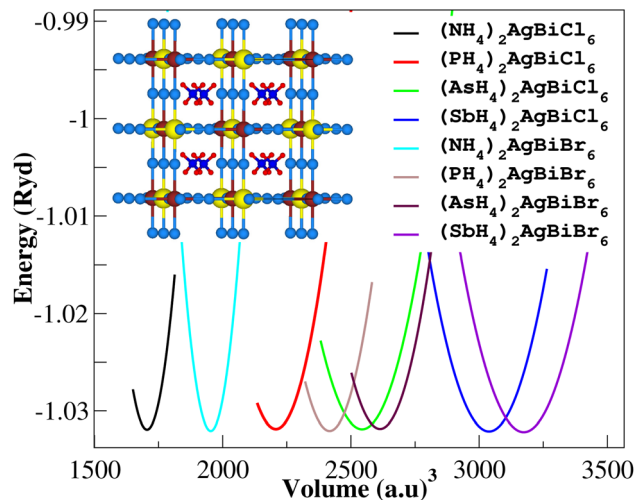


Fig. 2 Volume optimization curves of $X_2\text{AgBiY}_6$.

and $\text{Cs}_2\text{AgBiBr}_6$, which are 2.77 eV and 2.19 eV, respectively.¹⁸ We have determined the bandgaps for $\text{Cs}_2\text{AgBiBr}_6$ to be 1.16 eV without SOC, 0.961 eV with SOC, and 2.17 eV with mBJ + SOC. For $\text{Cs}_2\text{AgBiCl}_6$, however, the bandgap values are 2.63 eV with mBJ + SOC, 1.40 eV with SOC, and 1.69 eV without SOC. For the first-Brillouin-zone results depicted in Fig. 3 and 4, the $X_2\text{AgBiY}_6$ electronic band structures were investigated at a high-symmetry point ($X = \text{Cl}, \text{Br}$). The band structures revealed an indirect bandgap for the DPs that included the conduction band's L minima and valence band's X and maxima at the L-X equilibrium point. On both a theoretical and practical level, lead-free DPs exhibit an indirect bandgap. Since we recently determined the bandgaps for $(\text{NH}_4)_2\text{AgBiBr}_6$ (1.58 eV) and $(\text{SbH}_4)_2\text{AgBiBr}_6$ by using mBJ + SOC to achieve bandgap values near to the MAPI experimental value, we were able to acquire indirect bandgaps comparable to MAPI.³³ Therefore, we draw the conclusion that the FP-LAPW + lo approach significantly underestimates bandgap values in the double perovskites until the addition of mBJ + SOC. In order to replace MAPI at room temperature, we must therefore find a material that is lead-free

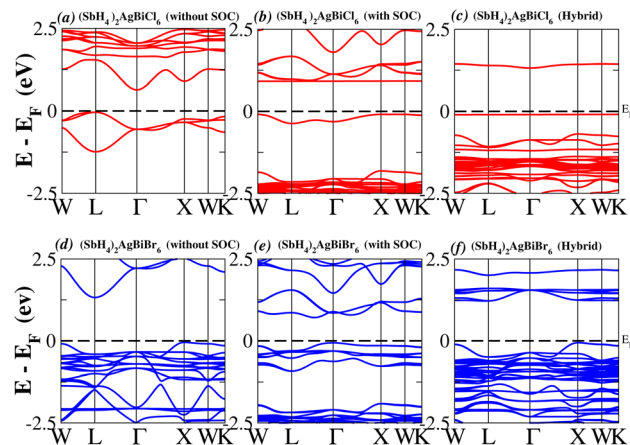


Fig. 4 Band structure of $(\text{SbH}_4)_2\text{AgBiY}_6$.

and has a bandgap value that is almost comparable to 1.6 eV.³⁴ Table 1 provides calculated bandgap values calculated with and without SOC, and with mBJ and SOC, for all materials. Referring to Table 1, it becomes evident that only $(\text{NH}_4)_2\text{AgBiBr}_6$ (1.58 eV) and $(\text{SbH}_4)_2\text{AgBiBr}_6$ have small bandgap values of 1.75 eV and 1.44 eV, respectively, for mBJ + SOC. On the other hand, the bandgap values for the rest of the compounds exceed 1.80 eV, as shown in Table 1. These materials exhibit a very high bandgap when mBJ + SOC is applied, rendering them inappropriate for solar cell applications, although they are fit for photocatalytic applications.

We determined bandgap values for $X_2\text{AgBiY}_6$ materials without SOC, with SOC, and with the hybrid calculation, as shown in Table 1. According to Fig. 3(a) and (b), and 4(a) and (b), $(\text{NH}_4)_2\text{AgBiBr}_6$'s bandgap value is 0.97 eV without SOC, and 0.88 eV with SOC, and similarly for $(\text{SbH}_4)_2\text{AgBiBr}_6$, the bandgap value is 1.32 eV without SOC, and 1.036 eV with SOC, which indicates that SOC not only reduces the bandgap values but also causes splitting of the conduction band minima (CBM). We were able to use SOC to detect a small reduction in the bandgap values for $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ of up to 94 meV and 277 meV, respectively. The band structures for

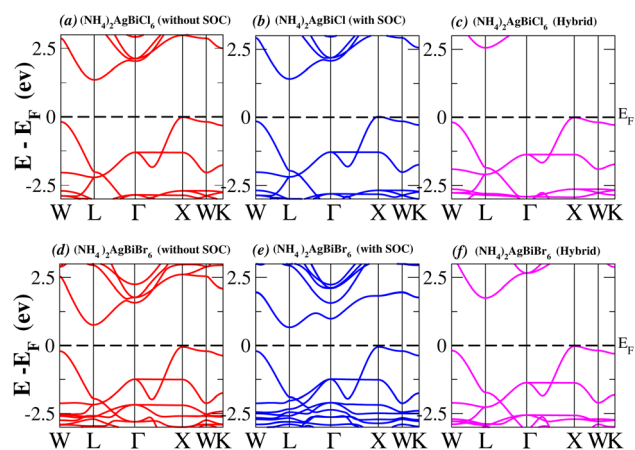


Fig. 3 Band structure of $(\text{NH}_4)_2\text{AgBiY}_6$.

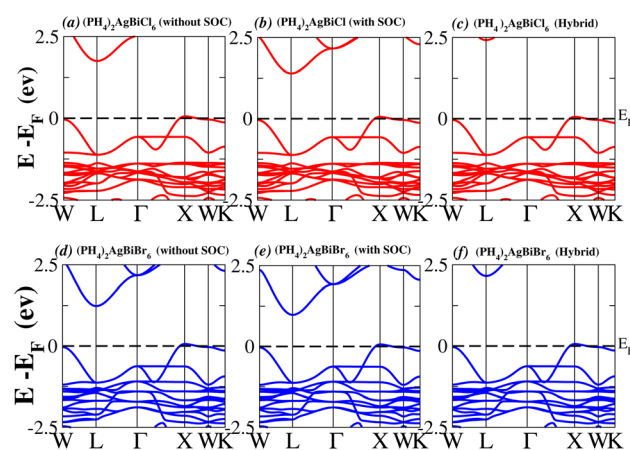
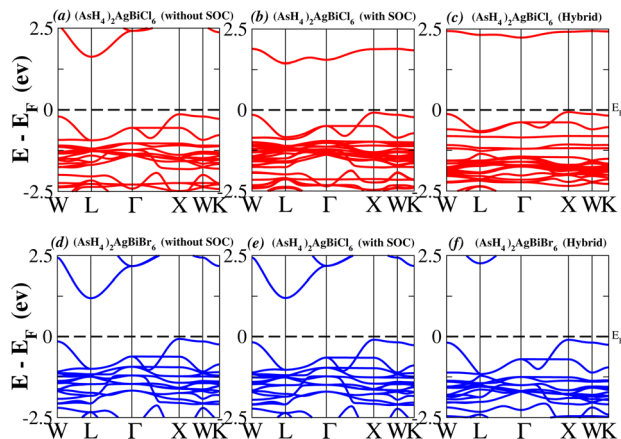
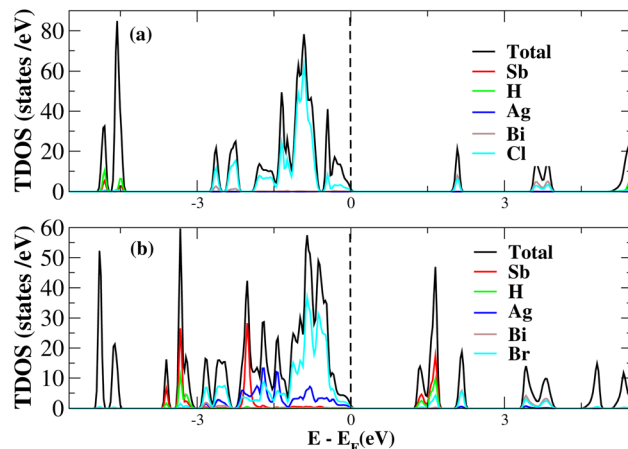
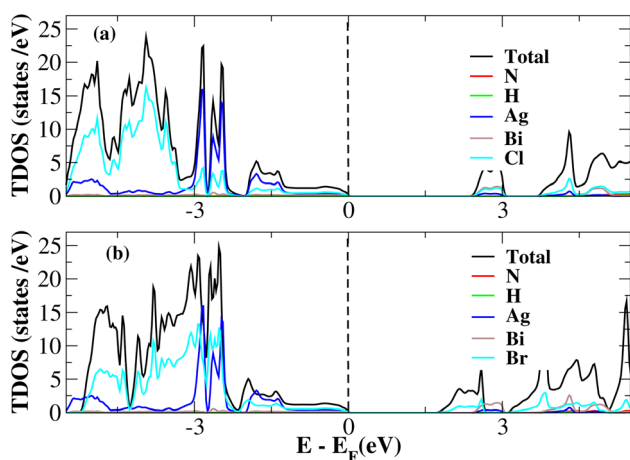


Fig. 5 Band structure of $(\text{PH}_4)_2\text{AgBiY}_6$.



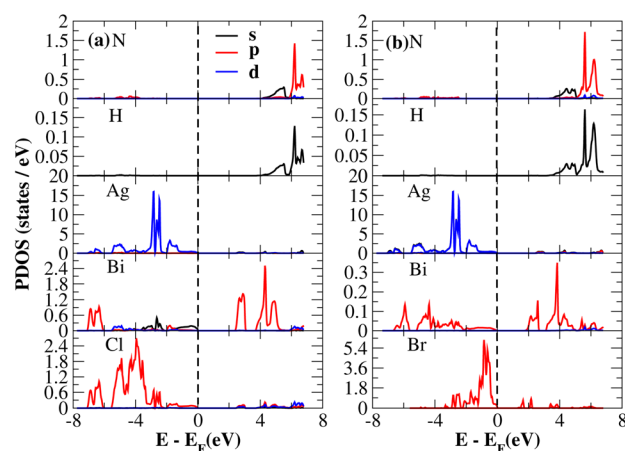
Fig. 6 Band structure of $(\text{AsH}_4)_2\text{AgBiY}_6$.Fig. 8 Total DOS of $(\text{SbH}_4)_2\text{AgBiY}_6$.Fig. 7 Total DOS of $(\text{NH}_4)_2\text{AgBiY}_6$.

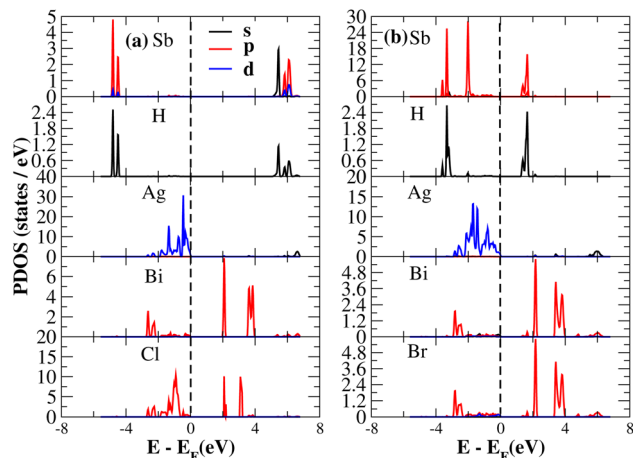
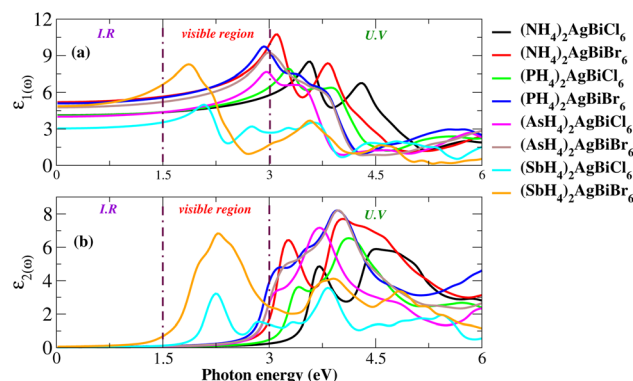
$(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ were subsequently calculated using the hybrid model [see Fig. 3(f) and 4(f)]. The calculated indirect bandgap values for $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ are 1.75 eV and 1.44 eV, respectively. When we calculated the bandgaps of PH_4 and AsH_4 cations with Cl or Br using the hybrid method (shown in Fig. 5 and 6), they were higher than 2 eV because SOC did not strongly effect the splitting of the CBM, as shown in Table 1. The bandgap values of $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ are closer to the values of $\text{CH}_3\text{NH}_3\text{PbX}_3$ ($\text{X} = \text{Cl}, \text{Br}, \text{I}$) determined experimentally. We can create an effective semiconductor solar cell material with bandgaps in the region between 1.0 and 1.8 eV. Electrons can be discharged in this bandgap range without generating a significant quantity of heat. Even though the indirect bandgap for double perovskite was recently discovered. While some materials have bandgap values that fall within the specified range, pressure-induced bandgap tuning may be used to achieve bandgap values that are nearly 1.5 eV.

After investigating the band structures, a study of the electrical characteristics followed. The bandgap between the valence band and the conduction band in the Fermi level in

these materials causes them to exhibit semiconducting characteristics, as indicated by the plot of the total density of states (TDOS) of $(\text{NH}_4)_2\text{AgBiY}_6$ ($\text{Y} = \text{Cl}, \text{Br}$) and $(\text{SbH}_4)_2\text{AgBiY}_6$ ($\text{Y} = \text{Cl}, \text{Br}$) in Fig. 7 and 8, respectively. A chemical difference serves as the main cause of the indirect bandgap, and the presence of the Ag atom's 4d state contributes to the compact bandgap in X_2AgBiY_6 . For the X_2AgBiY_6 compounds, the partial density of states (PDOS) comprises the antibonding states of the Ag atom's 4d orbitals and Br atom's 4p orbitals, as well as the valence band maxima.

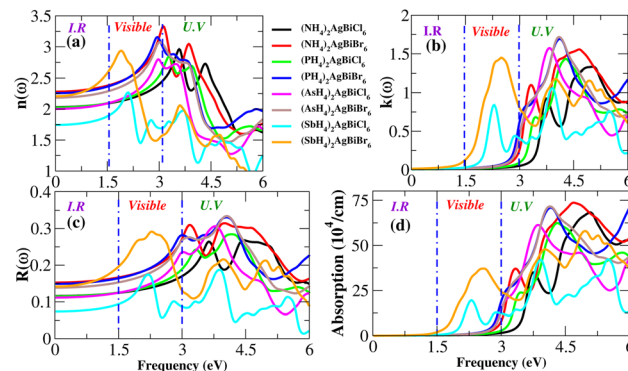
The PDOS of $(\text{NH}_4)_2\text{AgBiY}_6$ ($\text{Y} = \text{Cl}, \text{Br}$) and $(\text{SbH}_4)_2\text{AgBiY}_6$ ($\text{Y} = \text{Cl}, \text{Br}$) are depicted in Fig. 9 and 10, respectively. The PDOS provides details about how certain atoms contribute to structural stability. For the X_2AgBiY_6 compounds, the PDOS comprises the antibonding states of the Ag atom's 4d orbitals and Br atom's 4p orbitals as well as the valence band maxima. The 6p-state of Bi and the 4p-state of Cl/Br antibonding states formed the DP compounds in PDOS. This demonstrates how the H-s orbital for material slightly recedes. This demonstrates H-s orbital contribution is deep in the valence band. Important contributions come from the (Ag-d), (Bi-p), and (Cl/Br-p) states,

Fig. 9 Partial DOS of $(\text{NH}_4)_2\text{AgBiY}_6$.

Fig. 10 Partial DOS of $(\text{SbH}_4)_2\text{AgBiY}_6$.Fig. 11 Dielectric function for X_2AgBiY_6 .

which are depicted in Fig. 9 and 10. Both of these DPs can be used for indirect bandgap engineering in solar cell applications.

For an understanding of the importance of the predicted materials for solar cell applications, their optical properties were rigorously studied. For solar cell applications, we focused on two compounds, namely $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$. Research was undertaken into the optical performance of the transition from the valence band to the conduction band. The interaction of light and objects reveals optical characteristics. For optoelectronic devices, the strength of light absorption and emission depends on the transition between and within bands. Research on the relationship between optoelectronic characteristics and the dielectric function, absorption coefficient, complex refractive-index, and reflectivity R is available. The dielectric functions are described by $\epsilon(\omega) = \epsilon_1(\omega) + i\epsilon_2(\omega)$. Fig. 11(a and b) show the dielectric function plot with an energy range of 0 to 6 eV. The dielectric constant has two parts: the real part, represented by ϵ_1 , and the imaginary part, represented by ϵ_2 . The 0 Hz limit of the ϵ_1 spectrum exclusively describes the electronic component of the dielectric function, its most significant component. In Fig. 11(a), ϵ_0 increased from 3 to 5.7. Peaks at 1.75 eV for $(\text{SbH}_4)_2\text{AgBiBr}_6$ and 3.2 eV for $(\text{NH}_4)_2\text{AgBiBr}_6$ are the highest-energy peaks that have been recorded

Fig. 12 Optical properties (n , k , R , absorption) of X_2AgBiY_6 .

for these compounds. Thus, according to Penn's model,^{35,36} the bandgap and static-dielectric constant ϵ_0 are related to one another. A possible inter-band transition caused by light-energy absorption has been connected to ϵ_2 . This can be seen in Fig. 11(b), where light absorption mostly targets the visible portions of the two predicted molecules. $(\text{SbH}_4)_2\text{AgBiBr}_6$'s smaller bandgap polarizes electron transfer in the conduction band and improves the photovoltaic outcomes. An extensive analysis of ϵ_1 and ϵ_2 revealed that both $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ were capable of absorbing light with a substantial wavelength amplitude in the energy range of 1 to 4 eV. These combinations should not be ignored as they work well with a variety of solar cell technologies.

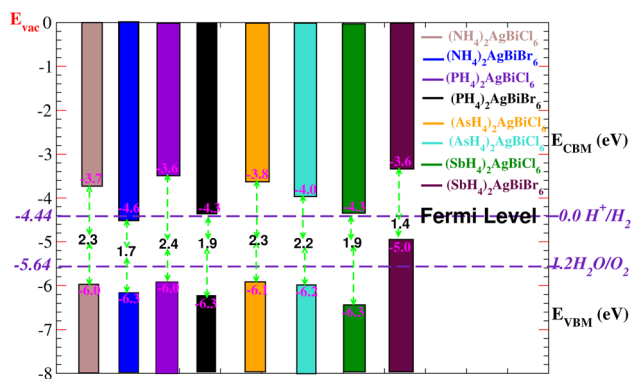
Light absorption is expressed by the absorption coefficient. In the visible spectrum, absorption weakened in the material under investigation. The obtained value of the absorption coefficient for the calculated compounds is illustrated in Fig. 12(d). The chemical compounds $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ apparently have high absorption coefficients, as indicated by their strong absorption peaks with heights of $37 \times 10^4 \text{ cm}^{-1}$ at 2.8 eV and $70 \times 10^4 \text{ cm}^{-1}$ at 4.7 eV, respectively. Due to the DFT-based approximation, the effects of ϵ_2 and $\alpha(\omega)$ have been compared to a lesser overestimation for the absorption coefficient peak.^{37,38} In the case of opto-electronic applications, the refractive index $n(\omega)$ and reflectivity $R(\omega)$ have been important factors that characterize the right kind of material.

For $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$, $n(\omega)$ and $R(\omega)$ have been displayed in Fig. 12(a and c). $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ have static refractive index values of 2.4 eV and 2.2 eV, respectively. The peak value is constant since the value of $n(\omega)$ is a copy of ϵ_1 . According to Fig. 12(c), $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ have full reflection $R(\omega)$ values of 0.07 and 0.05, respectively. According to Drude's model,³⁹ those materials light waves in the visible area may be superluminal for both materials. Following a thorough examination of those DP's optical properties, it was discovered that their significant absorption in the visible to UV spectrum enhances the likelihood that they could be used in solar cell systems. The dissipation of electromagnetic waves in materials is referred to as $K(\omega)$. The trends of $n(\omega)$ and $K(\omega)$ of $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$, respectively, are found to be very similar to those of the real and



Table 2 Optical parameters of $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$

Parameters	$(\text{NH}_4)_2\text{AgBiBr}_6$	$(\text{SbH}_4)_2\text{AgBiBr}_6$
$\epsilon_1(0)$	3.80	5.7
$n(0)$	2.5	2.2
$R(0)$	0.07	0.05
$k(0)$	4.6	2.7

Fig. 13 Photocatalytic properties of X_2AgBiY_6 . The standard oxidation potential $V_{\text{O}_2/\text{H}_2\text{O}}$ and standard reduction potential $V_{\text{H}^+/\text{H}_2}$ for water splitting are -5.67 eV and -4.44 eV (with the latter set as the Fermi level), respectively.

imaginary parts of the dielectric functions, especially where the peaks are located, indicating that the calculated results are in complete compliance with the relationships between the optical parameters (Table 2).

Solar energy can be effectively used by semiconductors with an appropriate bandgap in order to split water molecules and produce hydrogen,^{40,41} therefore, clean renewable energy can be generated using photocatalytic water splitting. The electrons (holes) reduce (oxidize) water during the photocatalytic reaction.⁴² Therefore, the semiconductor's bandgap needs to be greater than 1.23 eV (Fig. 13). Mulliken electronegativity is used to study photocatalytic water splitting for X_2AgBiY_6 . $E_{\text{VBM}} = \chi - E_{\text{elec}} + 0.5 E_{\text{g}}$ and $E_{\text{CBM}} = E_{\text{VBM}} + E_{\text{g}}$.^{43,44} Photocatalytic water splitting for X_2AgBiY_6 is studied using Mulliken electronegativity (χ), standard electrode potential on the hydrogen scale ($E_{\text{elec}} = 4.5$ eV), bandgap (E_{g}), energies of valence (E_{VBM}), and conduction (E_{CBM}) band edge potentials at pH = 0. It is noticeable that the standard oxidation and reduction potentials

on the hydrogen scale for photocatalytic water splitting are -4.44 eV (set as the Fermi level) and -5.64 eV, respectively. To determine the band-edge positions of the conduction band (CB) and valence band (VB) with reference to standard oxidation on the hydrogen scale, the Fermi level is set to -4.44 eV.⁴⁵

At pH = 0, the VB and CB are set to 1.23 eV and 0 eV correspondingly, which correspond to -5.67 eV and -4.44 eV.⁴⁴ The VB and CB potentials were estimated for X_2AgBiY_6 using the mBJ + (WC-GGA) functional range. The borders of the common redox band satisfy the conditions for water splitting at pH = 0. Out of eight compounds, six compounds show very good photocatalytic properties. $(\text{NH}_4)_2\text{AgBiBr}_6$ is not good for reduction purposes and $(\text{SbH}_4)_2\text{AgBiBr}_6$ is not good for oxidation purposes. On the other hand, all materials except these two have potentials more positive than the necessary VB potential, indicating good reactions for the oxidation of water. Furthermore, it is evident from Fig. 13 that six materials under study exhibit positions for the E_{VB} band edges that are outside of the reduction potentials that are energetically appropriate. Thus, we reach the conclusion that these materials under consideration are viable options for the industrial generation of solar hydrogen.

Effective elastic constants are crucial for appropriate practical applications of a material. The stability of a structure and a material's reaction to outside forces are both described by the elastic constant. Table 3 lists the computed elastic constants of X_2AgBiY_6 . Experimental results are not accessible for comparison with our predicted values. Both materials satisfy the $C_{11} > 0$, $C_{44} > 0$, $C_{11} + 2C_{12} > 0$, $C_{11} - C_{12} > 0$ and $C_{12} > B > C_{11}$ stability criteria for cubic crystals.^{46,47} This demonstrates the elastic stability of both the materials listed above against deformation forces. The elastic constant is being studied in order to calculate the mechanical characteristics using the conventional relations mentioned in Table 3.^{48,49} The material's plastic deformation in response to applied stress is measured using the shear modulus G_{H} . The fact that $(\text{NH}_4)_2\text{AgBiBr}_6$ has higher Young's modulus (Y) and shear modulus (G_{H}) values than $(\text{Sb}_4)_2\text{AgBiBr}_6$ proves that it is stiffer and offers more resistance to plastic deformation. The B/G (Pugh ratio) reveals the ductile and brittle behavior of a material.⁵⁰ It is evident from Table 3 that all materials are ductile because their B/G ratios are greater than 1.75 (the crucial number). The positive or negative values of Cauchy pressure can also be used to indicate a material's ductile or brittle nature ($C'' = C_{12} - C_{44}$). The positive value of C'' (in Table 3) also

Table 3 Elastic lattice parameters of X_2AgBiY_6

Compound	C_{11}	C_{12}	C_{44}	G_{V}	G_{R}	G_{H}	Y	B/G	C''	ν	A	C'
$(\text{NH}_4)_2\text{AgBiCl}_6$	79.19	22.70	18.36	22.31	21.35	21.83	56.76	1.90	4.34	0.27	0.65	28.24
$(\text{NH}_4)_2\text{AgBiBr}_6$	84.73	31.04	19.02	22.15	21.53	21.84	58.73	2.25	5.02	0.30	0.70	26.84
$(\text{PH}_4)_2\text{AgBiCl}_6$	77.97	28.51	21.98	23.08	23.00	23.04	59.13	1.95	6.52	0.28	0.88	24.72
$(\text{PH}_4)_2\text{AgBiBr}_6$	82.98	31.31	24.11	24.80	24.77	24.79	63.58	1.94	7.20	0.27	0.93	25.83
$(\text{AsH}_4)_2\text{AgBiCl}_6$	73.37	29.66	21.54	21.66	21.66	21.70	55.88	2.04	8.12	0.28	0.98	21.85
$(\text{AsH}_4)_2\text{AgBiBr}_6$	74.83	27.15	21.52	22.45	22.39	24.43	57.37	1.91	5.64	0.27	0.90	23.84
$(\text{SbH}_4)_2\text{AgBiCl}_6$	72.21	28.84	20.26	20.83	20.81	20.83	53.85	2.0	8.54	0.29	0.93	21.68
$(\text{SbH}_4)_2\text{AgBiBr}_6$	73.38	26.95	19.18	20.79	20.61	20.70	52.30	2.12	7.78	0.28	0.82	23.21

indicates good ductility of $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$. The Poisson's ratio (ν) shows how resistant a crystal is to compression. Due to the low values of ν , all materials are determined to be stable in the presence of shear stress. Table 3 lists the values of the anisotropic constant (A) for $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$. The deviation of A from unity can be used to gauge the anisotropy of a material. It is evident from the table that the anisotropic factor is less than unity, and as a result, the properties of the material alter in various crystallographic directions. The shear constant C indicates the material's dynamic stability against tetragonal distortion. For dynamic stability, C must be bigger than 0 (positive values).⁵¹ As shown in Table 3, the fact that all materials have values of C that are greater than 0 shows that they are mechanically stable.

4. Conclusions

Double perovskites $\text{X}_2\text{Ag}^{1+}\text{Bi}^{3+}\text{X}_6$ ($\text{X} = \text{NH}_4, \text{PH}_4, \text{AsH}_4, \text{SbH}_4$, and $\text{Y} = \text{Cl}, \text{Br}$) were investigated using density functional theory. Investigations were done on the structural, electronic, optical, photocatalytic, and elastic properties. These compounds' bandgaps were computed. From these compounds, only $(\text{NH}_4)_2\text{AgBiBr}_6$ and $(\text{SbH}_4)_2\text{AgBiBr}_6$ had bandgaps of 1.76 eV and 1.44 eV, respectively. The remaining materials all exhibit bandgap values greater than 2 eV when the mBJ adjustment is applied. In contrast to partial density of states results, which show Cl's p-orbital bands and Sb's s-orbital bands, the total density of state (DOS) results present Cl and Br as significant contributors to the valence band maxima (VBM) and Ag as a contributor to the conduction band minima (CBM). We investigated optical characteristics to determine the absorption coefficients of X_2AgBiY_6 ($\text{NH}_4, \text{PH}_4, \text{AsH}_4, \text{SbH}_4$ and $\text{Y} = \text{Cl}, \text{Br}$) and we learned that, based on the bandgap values and optical absorption, $(\text{SbH}_4)_2\text{AgBiBr}_6$ is the best suited option among all other examined compounds for solar cell use. We determined that six compounds are suitable for redox reactions based on their photocatalytic characteristics. The stability, indirect bandgap value, and optical absorption values that are close to MAPI make these perovskites a good choice for lead-free hybrid solar cells. Their stability has been established by their mechanical characteristics.

Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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